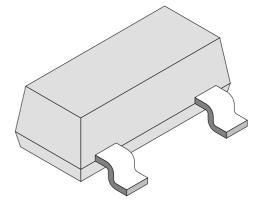
Vishay Telefunken

Switching Diodes

Features

- Silicon planar epitaxial high speed diode
- For switching and general purpose applications



94 8550

Order Instruction

Type	Type Differentiation	Ordering Code	Remarks
BAS19	$V_{RRM} = 120 \text{ V}$	BAS19-GS08	Tape and Reel
BAS20	$V_{RRM} = 200 V$	BAS20-GS08	Tape and Reel
BAS21	V _{RRM} = 250 V	BAS21-GS08	Tape and Reel

Absolute Maximum Ratings

 $T_i = 25^{\circ}C$

Parameter	Test Conditions	Type	Symbol	Value	Unit	
Mantine and an area attached		BAS19		100	V	
Working peak reverse voltage= DC Blocking voltage		BAS20	$V_{RWM} = V_{R}$	150		
DC Blocking voltage		BAS21	VR	200		
		BAS19		120	V	
Repetitive peak reverse voltage		BAS20	V_{RRM}	200		
		BAS21		250		
Book forward ourgo ourrent	t=1μs			2.5	Λ	
Peak forward surge current	t=1s		I _{FSM}	0.5	A	
Repetitive peak forward current			I _{FRM}	625	mΑ	
Average forward current	t _p <0.3ms		I _{FAV}	200	mA	
Forward current	T _{Case} =T _L		I _F	400	mΑ	
Power dissipation	(8 mm from Case)= T _{amb}		P _{tot}	250	mW	
Junction and storage temperature range			T _j =T _{stg}	<i>–</i> 55+150	°C	

Maximum Thermal Resistance

 $T_i = 25^{\circ}C$

Parameter	Test Conditions	Symbol	Value	Unit
Junction to ambient		R _{th,JA}	500	K/W

BAS19-BAS21

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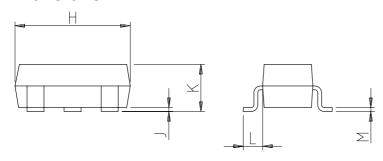
Electrical Characteristics

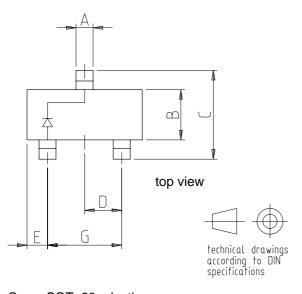
 $T_i = 25^{\circ}C$

Parameter	Test Conditions	Туре	Symbol	Min	Тур	Max	Unit
Forward voltage	I _F =100mA		V _F			1.0	V
	I _F =200mA					1.25	
Reverse current	$V_R=V_{Rmax}$		1			100	nA
Reverse current	V _R =V _{Rmax} , T _j = 150 °C		I _R			100	μΑ
Deveme breekdown	$I_R=100\mu A, t_p<0.3ms$	BAS19	V _{(BR)R}	120			V
Reverse breakdown voltage	I _R =100μA	BAS20		200			V
	I _R =100μA, V _R <275 V	BAS21	, ,	250			V
Reverse recovery time	$I_F=I_R=10$ mA, $R_L=100\Omega$, $V_R=6$ V to $I_R=1$ mA. $R_L=100\Omega$		t _{rr}			50	ns
Diode capacitance	V _R =0, f= 1MHz		C_D			5	pF
Dynamic forward resistance	I _F =10mA		r _f		5		Ω

14370

Dimensions in mm





SOT-23			
Dim	Min	Max	
А	0.37	0.50	
В	1.19	1.40	
	2.10	2.50	
D	0.89	1.05	
Е	0.45	0.61	
G	1.78	2.05	
Н	2.79	3.05	
J	0.013	0.15	
K	0.89	1.10	
L	0.45	0.61	
М	0.076	0.130	
Al	All Dimensions in mm		

Case: SOT–23, plastic Terminals: Solderable per MIL–STD–202, Method 208

Approx. weight: 0.008 grams

Marking: BAS19 K80, BAS20 K81, BAS21 K82



Vishay Telefunken

Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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Document Number 85540 www.vishay.com
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